

ESD Protection Diodes Silicon Epitaxial Planar

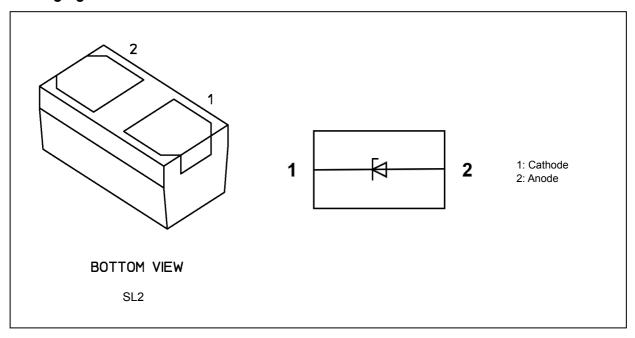
# DF2S10ASL

#### 1. Applications

· ESD Protection

Note: This product is designed for protection against electrostatic discharge (ESD) and is not intended for any other purpose, including, but not limited to, voltage regulation.

#### 2. Packaging and Internal Circuit



# 3. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Note	Rating	Unit
Electrostatic discharge voltage (IEC61000-4-2) (Contact)	V <sub>ESD</sub>	(Note 1)	±30	kV
Electrostatic discharge voltage (IEC61000-4-2) (Air)			±30	
Peak pulse power (t <sub>p</sub> = 8/20 μs)	P <sub>PK</sub>		60	W
Peak pulse current (t <sub>p</sub> = 8/20 μs)	I <sub>PP</sub>	(Note 2)	2.5	Α
Junction temperature	Tj		150	°C
Storage temperature	T <sub>stg</sub>		-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

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Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: According to IEC61000-4-2. Note 2: According to IEC61000-4-5.

Start of commercial production



## 4. Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

 $V_{\text{RWM}}$ : Working peak reverse voltage

Vz: Zener voltage

V<sub>BR</sub>: Reverse breakdown voltage

Z<sub>Z</sub>: Dynamic impedance

Iz: Zener current

I<sub>BR</sub>: Reverse breakdown current

IR: Reverse current

V<sub>R</sub>: Reverse voltage

V<sub>C</sub>: Clamp voltage I<sub>PP</sub>: Peak pulse current

R<sub>DYN</sub>: Dynamic resistance

I<sub>F</sub>: Forward current

V<sub>F</sub>: Forward voltage

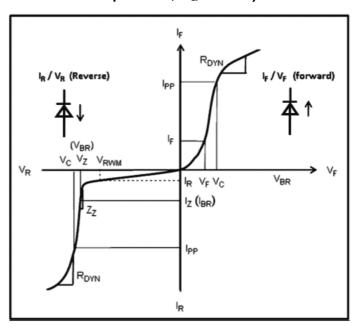


Fig. 4.1 Definitions of Electrical Characteristics

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Working peak reverse voltage	$V_{RWM}$		_	_	_	8	V
Zener voltage (Reverse breakdown voltage)	V <sub>Z</sub> (V <sub>BR</sub> )		I <sub>Z</sub> = 5 mA (I <sub>BR</sub> = 5 mA)	9.4	10.0	10.6	V
Dynamic impedance	Z <sub>Z</sub>		I <sub>Z</sub> = 5 mA (I <sub>BR</sub> = 5 mA)	_	_	30	Ω
Reverse current	I <sub>R</sub>		V <sub>RWM</sub> = 8 V	_	_	0.5	μА
Clamp voltage	V <sub>C</sub>	(Note 1)	I <sub>PP</sub> = 1 A	_	13.1	_	V
			I <sub>PP</sub> = 2.5 A	_	15.7	24	
		(Note 2)	I <sub>TLP</sub> = 16 A	_	22.5	_	V
			I <sub>TLP</sub> = 30 A	_	31	_	
Dynamic resistance	R <sub>DYN</sub>	(Note 2)	_	_	0.5	_	Ω
Total capacitance	Ct	(Note 3)	V <sub>R</sub> = 0 V, f = 1 MHz	_	16	_	pF

Note 1: Based on IEC61000-4-5 8/20 µs pulse.

Note 2: TLP parameter:  $Z_0 = 50 \Omega$ ,  $t_p = 100 \text{ ns}$ ,  $t_r = 300 \text{ ps}$ , averaging window: t = 30 ns to 60 ns, extraction of dynamic resistance using a least-squares fit of TLP characteristics at IPP between 8 A to 16 A.

Note 3: Guaranteed by design.



## 5. Marking

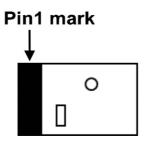


Fig. 5.1 Marking

# 6. Land Pattern Dimensions (for reference only)

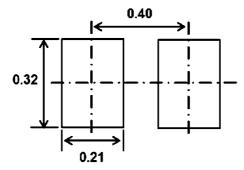
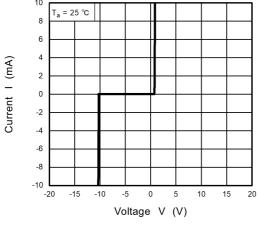


Fig. 6.1 Land Pattern Dimensions (Unit: mm)



## 7. Characteristics Curves (Note)



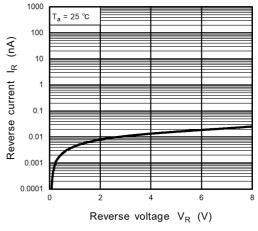
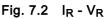


Fig. 7.1 I - V



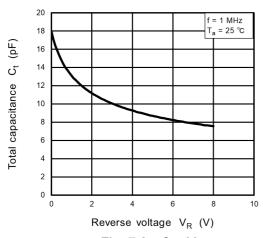
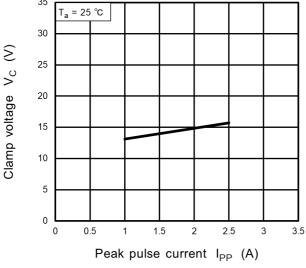


Fig. 7.3 Ct - VR

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## 8. Clamp Voltage - Peak Pulse Current (V<sub>C</sub> - I<sub>PP</sub>) (Note)



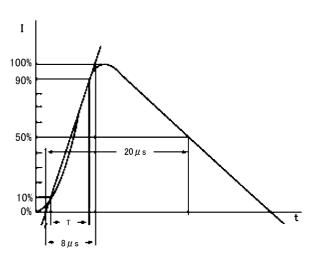


Fig. 8.1 V<sub>C</sub> - I<sub>PP</sub>

Fig. 8.2 Based on IEC61000-4-5 8/20  $\mu$ s pulse.(Ed.2)

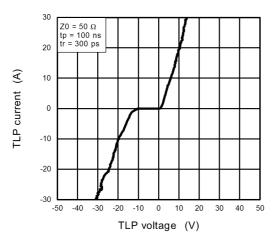
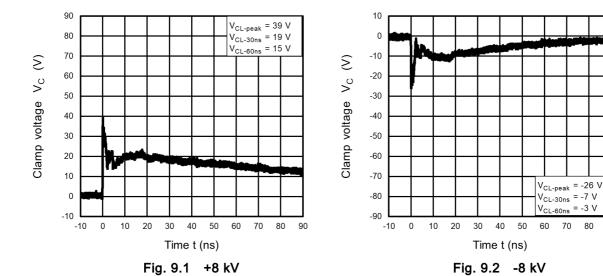


Fig. 8.3 TLP

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



#### 9. ESD Clamp Waveform (Note)



**ESD Tester** IEC61000-4-2 (contact)  $(C = 150 pF, R = 330 \Omega)$ Oscilloscope 100x Attenuator 100x 50 Ω DUT

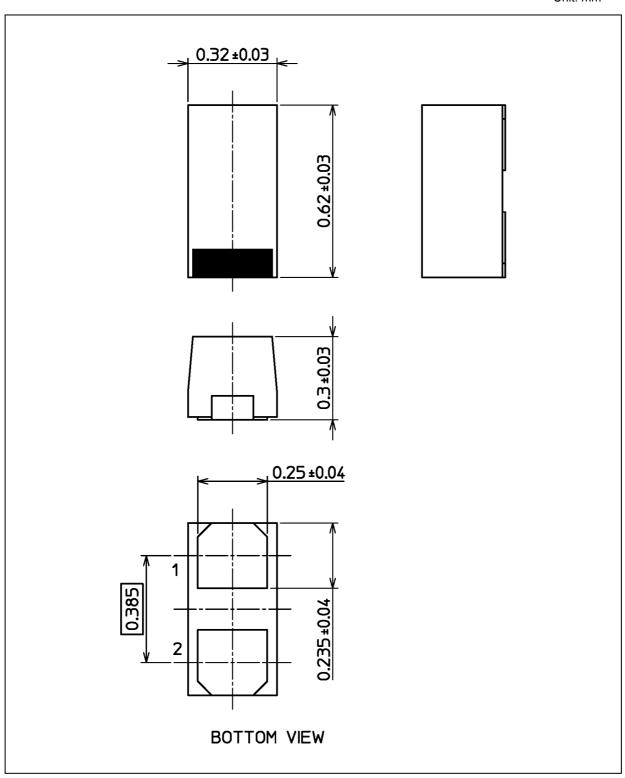
Fig. 9.3 IEC61000-4-2 (Contact)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## **Package Dimensions**

Unit: mm



Weight: 0.2 mg (typ.)

	Package Name(s)	
Nickname: SL2		



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